# imall

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ead has same dimensions

UMZ7N

0.2

## General purpose transistor (dual transistors)

## EMZ7 / UMZ7N

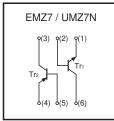
### Features

- 1) Both a 2SA2018 chip and 2SC5585 chip in a EMT or UMT package.
- 2) Mounting possible with EMT3 or UMT3
- automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.
- 5) Low VCE(sat)

### Structure

NPN / PNP epitaxial planar silicon transistor

#### Inner circuit



## • Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Lin	nits	Unit
Farameter	Symbol	Tr <sub>1</sub>	Tr <sub>2</sub>	Unit
Collector-base voltage	Vсво	15	-15	V
Collector-emitter voltage	Vceo	12	-12	V
Emitter-base voltage	Vebo	6	-6	V
Collector current	lc	500	-500	mA
Collector current	Іср	1	-1	А
Collector power dissipation	Pc	150(T	OTAL)	mW *1
Junction temperature	Tj	15	50	°C
Storage temperature	Tstg	–55 to	+150	°C

\*1 120mW per element must not be exceeded.

## ROHM : EMT6 EIAJ : SC-88 Abbreviated symbol : Z7 Abbreviated symbol : Z7

•Dimensions (Unit : mm)

Each lead has same dimensions

1.0

EMZ7

2

## • Electrical characteristics (Ta=25°C) Tr1 (NPN)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	15	_	-	V	Ic=10μA
Collector-emitter breakdown voltage	BVCEO	12	_	-	V	Ic=1mA
Emitter-base breakdown voltage	ВУево	6	_	-	V	Iε=10μA
Collector cutoff current	Ісво	-	_	0.1	μA	Vcb=15V
Emitter cutoff current	Іево	_	_	0.1	μΑ	VEB=6V
Collector-emitter saturation voltage	VCE(sat)	-	90	250	mV	Ic/IB=200mA/10mA
DC current transfer ratio	hfe	270	_	680	-	Vce/lc=2V/10mA
Transition frequency	fт	_	320	-	MHz	Vce=2V, Ic=-10mA, f=100MHz
Output capacitance	Cob	_	7.5	_	pF	VCB=10V, IE=0A, f=1MHz

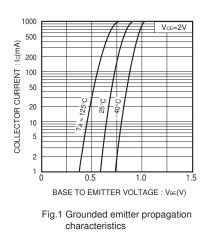
## Tr<sub>2</sub> (PNP)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-15	-	-	V	Ic=-10µA
Collector-emitter breakdown voltage	BVCEO	-12	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	BVEBO	-6	-	-	V	I <sub>E</sub> =-10μA
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb=-15V
Emitter cutoff current	Іево	-	-	-0.1	μΑ	VEB=-6V
Collector-emitter saturation voltage	VCE(sat)	-	-100	-250	mV	Ic/I <sub>B</sub> =-200mA/-10mA
DC current transfer ratio	hfe	270	-	680	-	Vce/lc=-2V/-10mA
Transition frequency	fт	-	260	-	MHz	Vce=-2V, Ic=10mA, f=100MHz
Output capacitance	Cob	-	6.5	_	pF	V <sub>CB</sub> =-10V, I <sub>E</sub> =0A, f=1MHz

## Packaging specifications

	Packaging type	Тарі	ng
	Code	TR	T2R
Part No.	Basic ordering unit (pieces)	3000	8000
UMZ7N		0	-
EMZ7		-	0

#### •Electrical characteristic curves Tr1 (NPN)



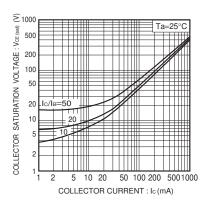


Fig.4 Collector-emitter saturation voltage vs. collector current (II)

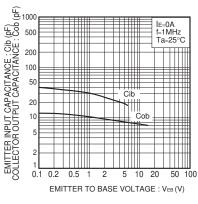
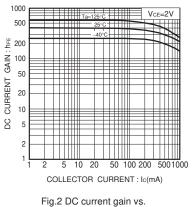


Fig.7 Collector output capacitance vs collector-base voltage Emitter input capacitance vs emitter-base voltage



g.2 DC current gain vs. collector current

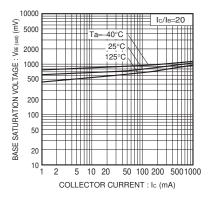
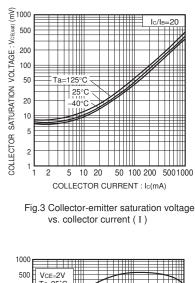


Fig.5 Base-emitter saturation voltage vs. collector current



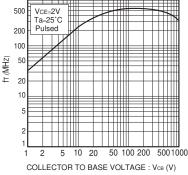
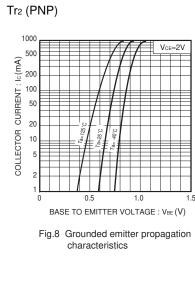


Fig.6 Collector output capacitance Emitter input capacitance vs. base voltage



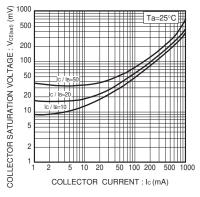
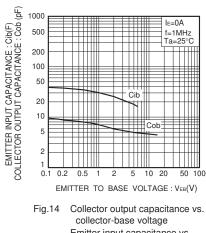
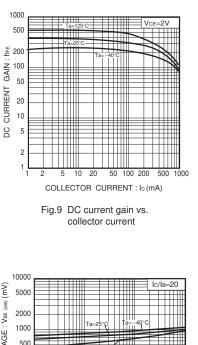


Fig.11 Collector-emitter saturation voltage vs. collector current



Emitter input capacitance vs. emitter-base voltage



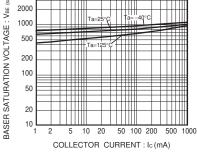


Fig.12 Base-emitter saturation voltage vs. collector current

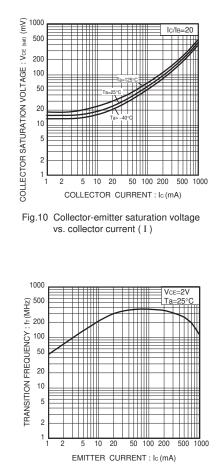


Fig.13 Gain bandwidth product vs. emitter current

	Notes
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